





The CHR70M is a high resolution CMOS image sensor with 10000 by 7096 pixels. The image array consists of 3.1µm x 3.1µm pinned diode pixels which

share a number of transistors (2 pixels sharing). The image sensor has 8 analog outputs, each running at 30MHz. This results in a frame rate of 3fps at full resolution. Higher frame rates can be achieved in windowing mode or subsampling mode.

The image sensor also integrates a programmable gain amplifier and offset regulation. These and other settings are all programmable using the SPI interface. All internal exposure and read out timings are generated by a programmable onboard sequencer. External triggering and exposure programming is also possible.

The CHR70M is derived from a custom CMOS image sensor. This sensor is not for sale for biometric applications.

Please contact CMOSIS for further information.

## **SPECIFICATIONS**

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Part status	Production		
Resolution	70MP - 10000 (H) x 7096 (V)		
Pixel size	3.1 x 3.1		
Optical format	35mm		
Shutter type	Electronic rolling shutter		
Frame rate	3 fps		
Output interface	8 analog channels		
Sensitivity	0,88 V/lux.s		
Conversion gain	64 uV/e-		
Full well charge	13000 e-		
Dark noise	7 e- (RMS)		
Dynamic range	63 dB		
SNR max	41,1 dB		
Parasitic light sensitivity	-		
Extended dynamic range	No		
Dark current	3,2 e-/s (25 degC)		
Fixed pattern noise	< 0,09% of full swing)		
Chroma	Mono and RGB		
Supply voltage	3,3V		
Power	435 mW		
Operating temperature range	0 to +60 degC (TBC)		
RoHS compliance	Yes (TBC)		
Package	65 pins PGA		
Socket	Andon Electronics (http://www.andonelectronics.com) 575-13-85-065-01M-R27-L14 (thru- hole) 575-13-85-065-93M-R27-L14 (surface mount)		

## ORDERING INFO - CHR70M

Part Number	Version	Chroma	Microlens	Package	Glass
CHR71000-1E5M1PA	5 μm epi	mono	Yes	Ceramic PGA	double sided AR coated
CHR71000-1E5C1PA	5 μm epi	RGB Bayer	Yes	Ceramic PGA	double sided AR coated
CHR71000-1E5M1PN	5 μm epi	mono	Yes	Ceramic PGA	Removeable glass lid